Switch-Mode Power Rectifier

This ultrafast rectifier in the dual flag SO–8 flat lead package offers designers a unique degree of versatility and design freedom. The two devices are electrically independent and can be used separately, as common cathode, as common anode or in series as a function of board level layout. The exposed pad design provides low thermal resistance. The clip attach design creates a package with very efficient die size to board area ratio. While thermal performance is nearly the same as the DPAK package height and board footprint are less than half.

Features

- New Package Provides Capability of Inspection and Probe After Board Mounting
- Low Forward Voltage Drop
- 175°C Operating Junction Temperature
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free and Halide-Free Devices

Mechanical Characteristics:

- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94–0 @ 0.125 in.
- Lead Finish: 100% Matte Sn (Tin)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Device Meets MSL 1 Requirements

Applications

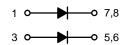
- Excellent Alternative to DPAK in Space—Constrained Automotive Applications
- Output Rectification in Switching Power Supplies
- Freewheeling Diode used with Inductive Loads



ON Semiconductor®

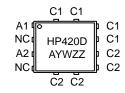
www.onsemi.com

ULTRAFAST RECTIFIER4 AMPERES (2x2), 200 VOLTS





MARKING DIAGRAM



HP420D = Specific Device Code A = Assembly Location

Y = Year
W = Work Week
ZZ = Lot Traceability

ORDERING INFORMATION

Device	Package	Shipping [†]
NRVHP420MFDT1G	DFN8 (Pb-Free)	1500 / Tape & Reel
NRVHP420MFDT3G	DFN8 (Pb-Free)	5000 / Tape & Reel
NRVHP420MFDWFT1G	DFN8 (Pb-Free)	1500 / Tape & Reel
NRVHP420MFDWFT3G	DFN8 (Pb-Free)	5000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

MAXIMUM RATINGS (per diode unless noted)

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	200	V
Average Rectified Forward Current (Rated V _R , T _C = 167°C)	I _{F(AV)}	2.0	А
Peak Repetitive Forward Current, (Rated V _R , Square Wave, 20 kHz, T _C = 165°C)	I _{FRM}	4.0	А
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	40	Α
Storage Temperature Range	T _{stg}	-65 to +175	°C
Operating Junction Temperature	TJ	−55 to +175	°C
Unclamped Inductive Switching Energy (10 mH Inductor, Non-repetitive)	E _{AS}	10	mJ
ESD Rating (Human Body Model)		2	
ESD Rating (Machine Model)		M4	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS (per diode unless noted)

Reverse Recovery Time $I_F = 3.0 \text{ A}, V_R = 30 \text{ V}, \text{ dl/dt} = 50 \text{ A/}\mu\text{s}, T_J = 25^{\circ}\text{C}$

Characteristic	Symbol	Тур	Max	Unit
Thermal Resistance, Junction–to–Case, Steady State (Assumes 600 mm² 1 oz. copper bond pad, on a FR4 board)	$R_{ heta JC}$	-	7.2	°C/W
ELECTRICAL CHARACTERISTICS (per diode unless noted)	-	-	=	-
Instantaneous Forward Voltage (Note 1) $ \begin{aligned} &(i_F=3.0 \text{ Amps, } T_J=125^\circ\text{C})\\ &(i_F=3.0 \text{ Amps, } T_J=25^\circ\text{C})\\ &(i_F=6.0 \text{ Amps, } T_J=125^\circ\text{C})\\ &(i_F=6.0 \text{ Amps, } T_J=25^\circ\text{C}) \end{aligned} $	VF	0.76 0.89 0.86 0.96	0.85 1.0 0.95 1.10	V
Instantaneous Reverse Current (Note 1) (Rated dc Voltage, T _J = 125°C) (Rated dc Voltage, T _J = 25°C)	i _R	1.00 0.03	35 0.5	μΑ

Reverse Recovery Time $I_F = 3.0 \text{ A}, V_R = 30 \text{ V}, \text{ dl/dt} = 50 \text{ A/}\mu\text{s}, T_J = 125^{\circ}\text{C}$ Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.

20

23

 t_{rr}

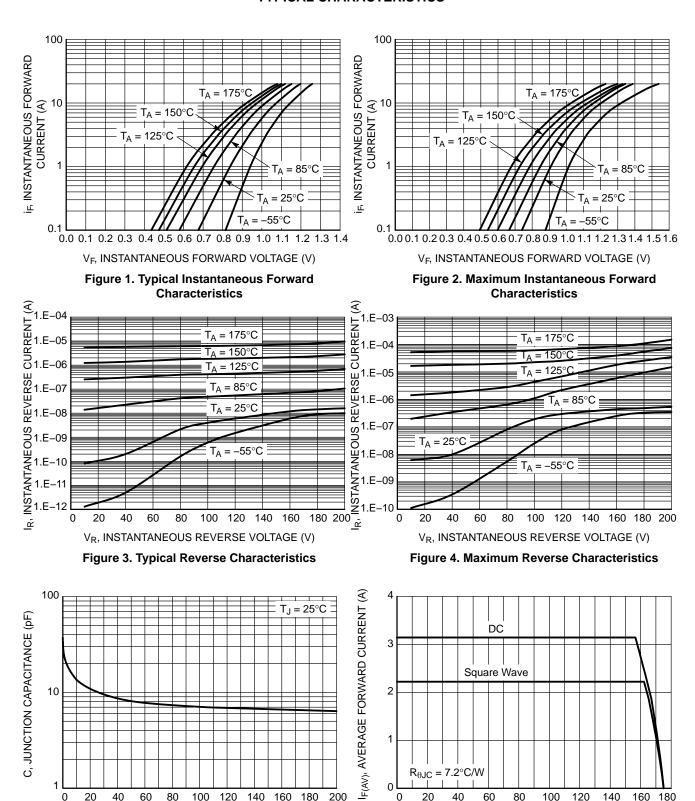
30

40

ns

ns

TYPICAL CHARACTERISTICS



 $\label{eq:VR} V_R,\, \text{REVERSE VOLTAGE (V)}$ Figure 5. Typical Junction Capacitance

 $\label{eq:TC} \textbf{T}_{C}, \text{CASE TEMPERATURE (°C)}$ Figure 6. Current Derating per Device

TYPICAL CHARACTERISTICS

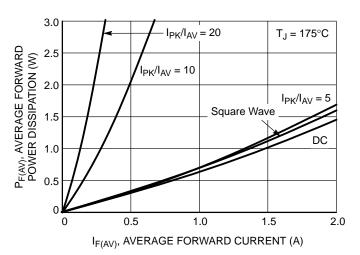


Figure 7. Forward Power Dissipation

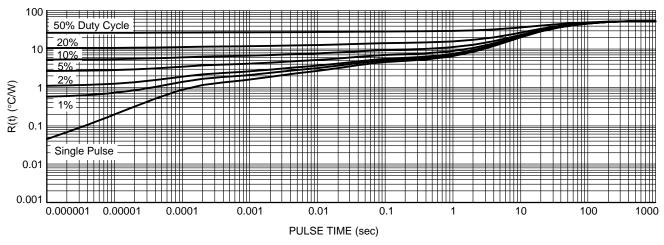
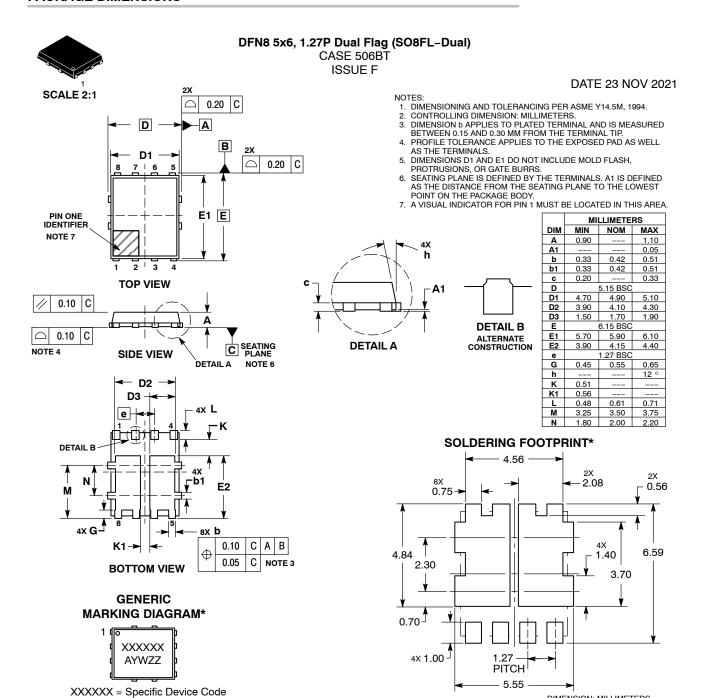


Figure 8. Typical Thermal Characteristics





*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

*	This information is generic. Please refer to
	device data sheet for actual part marking.
	Pb-Free indicator, "G" or microdot "■", may
	or may not be present. Some products may
	not follow the Generic Marking.

= Work Week

= Lot Traceability

= Year

Υ

W

77

DOCUMENT NUMBER:

= Assembly Location

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DESCRIPTION: DFN8 5X6, 1.27P DUAL FLAG (SO8FL-DUAL)

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PAGE 1 OF 1

DIMENSION: MILLIMETERS

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